

STR-W6753

Universal-Input/58 W Off-Line Quasi-**Resonant Flyback Switching Regulator**

ABSOLUTE MAXIMUM RATINGS
at T _A = +25°C
Control Supply Voltage, V _{CC} 35 V
Drain-Source Voltage, V _{DSS} 650 V
Drain Switching Current, Ip 11.2 A*
Peak Drain Switching Current,
I _{DM} 11.2 A
Single-Pulse Avalanche Energy,
E _{AS}
OCP/BD Voltage Range,
V _{OCP}
FB Input Current, I _{FB} 10 mA
FB Voltage Range, V _{FP} –0.5 V to +9 V
Package Power Dissipation, P _D
control ($V_{CC} \times I_{CC(ON)}$) 0.8 W
MOSFET (V _{DSS} × I _D) See Graph
MOSFET Channel Temp., T _J . +150°C
Internal Frame Temp., T _F +115°C
Operating Temperature Range,
T _A 20°C to +115°C†
Storage Temperature Range,
T _S 40°C to +125°C
* Drain switching current is limited by tem-
perature (page $\tilde{2}$) and safe operating area
(page 5).
†For the availability of parts meeting -40°C

The STR-W6753 is a quasi-resonant regulator specifically designed to satisfy the requirements for increased integration and reliability in switch-mode power supplies. It incorporates a primary control and drive circuit with an avalanche-rated power MOSFET. The regulator exhibits only low-level high-frequency EMI noise because of soft switching of the MOSFET close to ground (bottom point). A bottom-skip function minimizes an increase of operational frequency during light loads to improve system efficiency over the entire load range.

Covering the power range from below 120 watts for a 230 VAC input, or 58 watts for a universal input (85 to 264 VAC), this device can be used in a range of applications, from DVD and VCR players to ac adapters for cellular phones and digital cameras. An auto-standby function, which is internally triggered by sensing on time, reduces power consumption at light load. An externally triggered standby mode reduces the input power further. Multiple protections, including the avalanche-energy-guaranteed MOSFET, provide high reliability of system design. Devices with an increased output power rating are the STR-W6754 and STR-W6756.

Cycle-by-cycle current limiting, undervoltage lockout with hysteresis, and overvoltage protection protect the power supply during the normal overload and fault conditions. Overvoltage protection is latched after a short delay. The latch may be reset by cycling the input supply. Low start-up current and a low-power standby mode selected from the secondary circuit completes a comprehensive suite of features. The STR-W6753 is provided in a fully molded TO-220-style flangemounted, high power, isolated plastic package.

FEATURES AND BENEFITS

- Rugged 650 V Avalanche-Rated MOSFET Simplified Surge Absorption No V_{DSS} Derating Required
- **1**.7 Ω Maximum $\mathbf{r}_{DS(on)}$
- Two Operational Modes by Automatic Switching: Quasi-Resonant Mode for Normal Operation Burst Mode for Standby Operation or Light Loads
- Automatic or Manually Triggered Burst Standby Input Power <0.1 W at No Load
- Low Operating Current (6 mA typ)

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Always order by complete part number, e.g., |STR-W6753 .



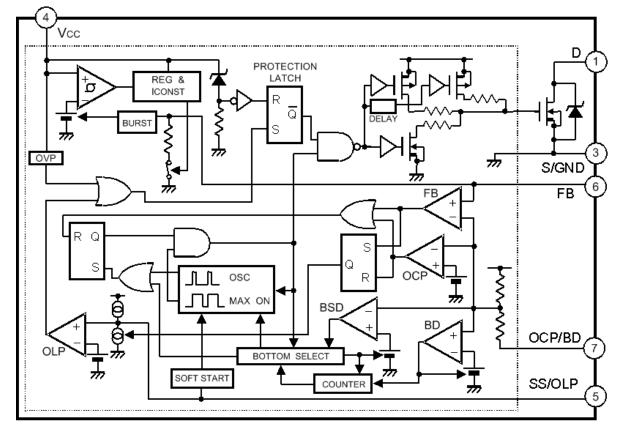
requirements, contact Allegro's Sales Represen-

tative.

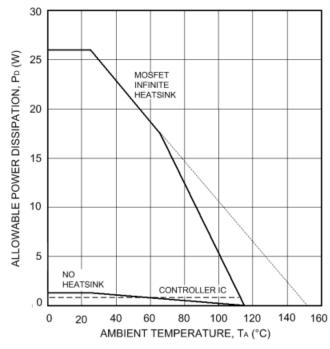
Sanken Power Devices from Allegro MicroSystems







FUNCTIONAL BLOCK DIAGRAM



FEATURES AND BENEFITS (cont'd)

- Auto-Bias Function
 Stable Burst Operation Without Generating Interference
- Internal Off-Timer Circuit
- Built-In Constant-Voltage Drive
- Multiple Protections: Pulse-by-Pulse Overcurrent Protection Overload Protection with Auto Recovery Latching Overvoltage Protection Undervoltage Lockout with Hysteresis
- RoHS Compliant



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ELECTRICAL CHARACTERISTICS at $T_A = +25$ °C, $V_{CC} = 20$ V, voltage measurements are referenced to S/GND terminal (unless otherwise specified).

Characteristic	Symbol	Test Conditions		Limits			
			Min.	Тур.	Max.	Units	
Start-Up Operation							
Operation Start Voltage	V _{CC(ON)}	Turn-on, $V_{CC} = 0 \rightarrow 19.9 V$	16.3	18.2	19.9	V	
Soft-Start Operation Stop Voltage	V _{SS/OLP}		1.1	1.2	1.4	V	
Soft-Start Oper. Charging Current	I _{SS/OLP}		-390	-550	-710	μA	
Operation Stop Voltage	V _{CC(OFF)}	Turn-off, V _{CC} = 19.9 → 8.8 V	8.8	9.7	10.6	V	
Circuit Current in Non-Operation	I _{CC(OFF)}	V _{CC} = 15 V	-	_	100	μA	
Normal Operation						-	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	I _D = 300 μA	650	_	_	V	
Drain Leakage Current	I _{DSS}	V _{DS} = 650 V	-	_	300	μA	
On-State Resistance	r _{DS(on)}	I _D = 1.4 A, T _J = +25°C	-	_	1.7	Ω	
Switching Time	tf		-	_	400	ns	
Circuit Current	I _{CC(ON)}		-	_	6.0	mA	
Oscillation Frequency	f _{osc}		19	22	25	kHz	
Bottom-Skip Oper. Threshold Volt.	V _{OCPBD(BS1)}		-605	-665	-720	mV	
	V _{OCPBD(BS2)}		-385	-435	-485	mV	
Quasi-Resonant Oper. Threshold	V _{OCPBD(TH1)}		280	400	520	mV	
	V _{OCPBD(TH2)}		670	800	930	mV	
Feedback-Pin Threshold Voltage	V _{FB(OFF)}		1.32	1.45	1.58	V	
Feedback-Pin Current	I _{FB(ON)}		600	1000	1400	μA	
Standby Operation						•	
Standby Operation Start Voltage	V _{CC(S)}	V _{CC} = 0 → 12.2 V	10.3	11.1	12.1	V	
Standby Oper. Start Volt. Interval	V _{CC}		1.10	1.35	1.65	V	
Standby Non-Operation Current	I _{CC(S)}	V _{CC} = 10.2 V	-	20	56	μA	
Feedback-Pin Current	I _{FB(ON)}	V _{CC} = 10.2 V	-	4.0	14	μA	
Feedback-Pin Threshold Voltage	V _{FB(S)}	V _{CC} = 12.2 V	0.55	1.10	1.50	V	
Minimum ON Time	t _{on(min)}		0.5	0.8	1.2	μs	

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ELECTRICAL CHARACTERISTICS at $T_A = +25$ °C, $V_{CC} = 20$ V, voltage measurements are referenced to S/GND terminal (unless otherwise specified).

			Limits							
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units				
Protection Operation										
OVP Operation Voltage	V _{CC(OVP)}	Turn-off, $V_{CC} = 0 \rightarrow 29.9 V$	25.5	27.7	29.9	V				
Maximum ON Time	t _{on(max)}		27.5	32.5	39.0	μs				
OLP Operation Voltage	V _{SSOLP}		4.0	4.9	5.8	V				
OLP Operation Current	I _{SSOLP}		-6.0	-11	-16	μA				
Overcurrent Detect. Threshold Volt.	V _{OCPBD(LIM)}		-0.895	-0.940	-0.995	V				
OCP/BD-Pin Current	I _{OCPBD}		-40	-100	-250	μA				
Latch Holding Current	I _{CC(H)}	$V_{CC} = 29.9 \Rightarrow V_{CC(OFF)} - 0.3 V$	-	45	140	mA				
Latch Release Voltage	V _{CC(L)}	V _{CC} = 29.9 → 6 V	6.0	7.2	8.5	V				
Other										
Thermal Resistance	$R_{ extsf{ heta}JF}$	Output junction-to-frame	_	_	2.0	°C/W				

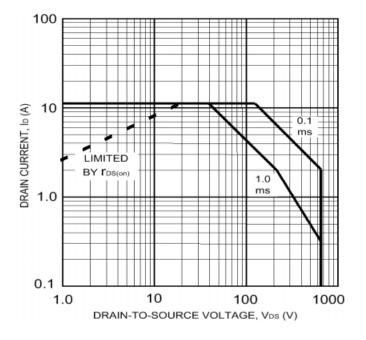
NOTES: 1. Typical Data is for design information only.

2. Negative current is defined as coming out of (sourcing) the specified device termninal.



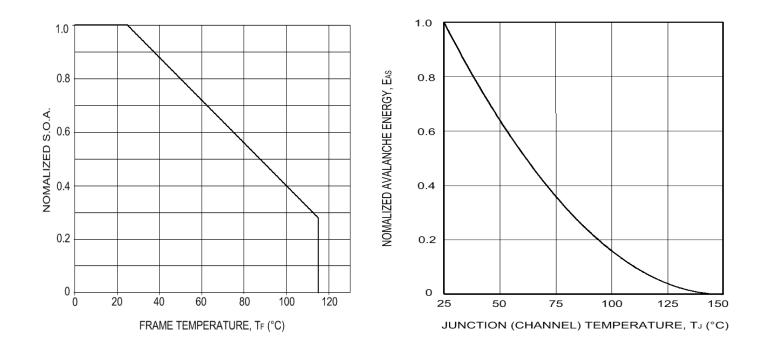






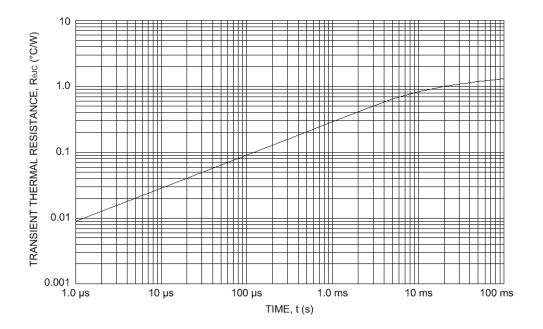
MOSFET TYPICAL CHARACTERISTICS

Avalanche energy is measured at V_{DD} = 99 V, L = 20 mH, I_L = 3.6 A.





MOSFET TYPICAL CHARACTERISTICS (cont'd)



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

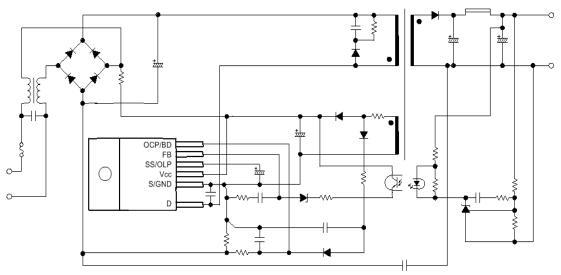


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APPLICATIONS INFORMATION



Typical Application

Complete product description and applications information is provided in Application Note 28103.30, *Series STR-W6750 Off-Line Quasi-Resonant Flyback Switching Regulators.*

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

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When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

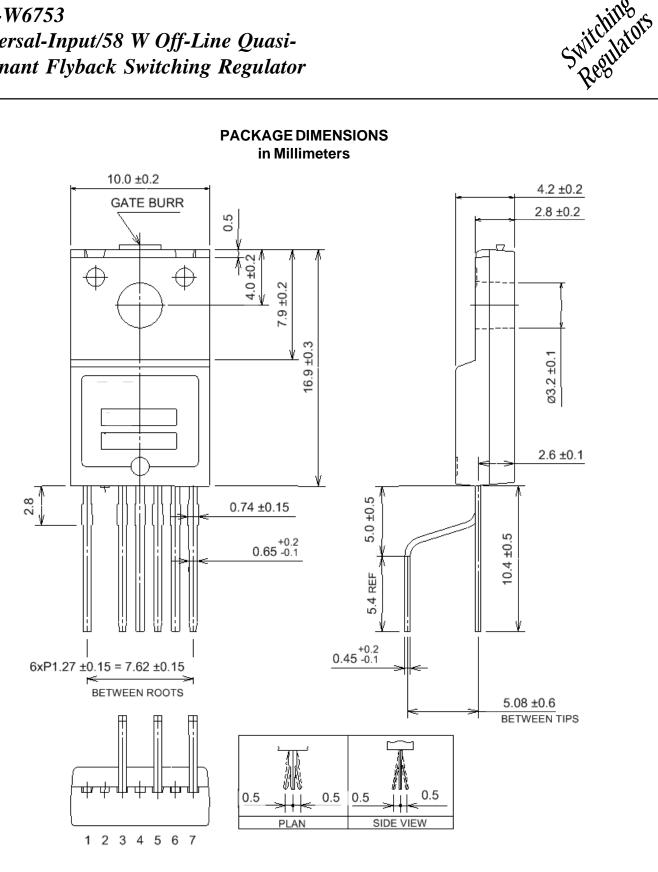
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Product weight: approx. 2.3 g.

Recommended mounting hardware torque: 0.588 ~ 0.785 Nm, 6 ~ 8 kgf x cm. Recommended silicon grease: Dow Corning SC102, Toshiba YG6260, Shin-Etsu G746, or equivalent.



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